

CURRENT LIMITING LOW SIDE DRIVER

Features

- Gate drive supply range from 12 to 18V
- Undervoltage lockout
- Current detection and limiting loop to limit driven power transistor current
- Error lead indicates fault conditions and programs shutdown time
- Output in phase with input
- 2.5V, 5V and 15V input logic compatible
- Also available LEAD-FREE

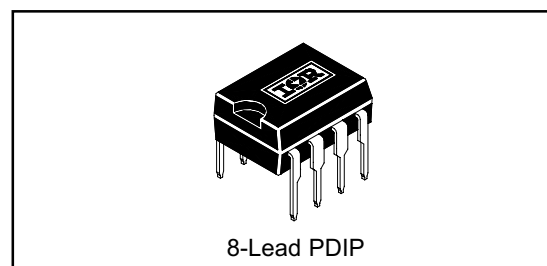
Description

The IR2121 is a high speed power MOSFET and IGBT driver with over-current limiting protection circuitry. Latch immune CMOS technology enables ruggedized monolithic construction. Logic inputs are compatible with standard CMOS or LSTTL outputs, down to 2.5V logic. The output driver features a high pulse current buffer stage designed for minimum cross-conduction. The protection circuitry detects over-current in the driven power transistor and limits the gate drive voltage. Cycle-by-cycle shutdown is programmed by an external capacitor which directly controls the time interval between detection of the over-current limiting condition and latched shutdown. The output can be used to drive an N-channel power MOSFET or IGBT in the low side configuration.

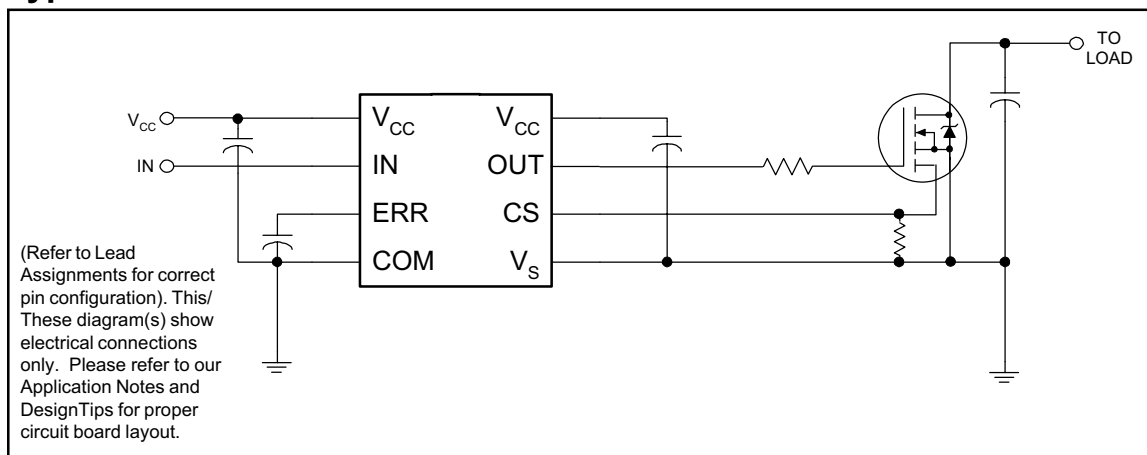
Product Summary

V_{OFFSET}	5V max.
I_{O+/-}	1A / 2A
V_{OUT}	12 - 18V
V_{CSth}	230 mV
t_{on/off} (typ.)	150 & 150 ns

Package



Typical Connection



IR2121 & (PbF)

Absolute Maximum Ratings

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

Symbol	Parameter Definition	Value		Units
		Min.	Max.	
V _{CC}	Fixed Supply Voltage	-0.3	25	V
V _S	Gate Drive Return Voltage	V _{CC} - 25	V _{CC} + 0.3	
V _O	Output Voltage	V _S - 0.3	V _{CC} + 0.3	
V _{IN}	Logic Input Voltage	-0.3	V _{CC} + 0.3	
V _{ERR}	Error Signal Voltage	-0.3	V _{CC} + 0.3	
V _{CS}	Current Sense Voltage	V _S - 0.3	V _{CC} + 0.3	
P _D	Package Power Dissipation @ T _A ≤ +25°C	—	1.0	W
R _{thJA}	Thermal Resistance, Junction to Ambient	—	125	°C/W
T _J	Junction Temperature	—	150	°C
T _S	Storage Temperature	-55	150	
T _L	Lead Temperature (Soldering, 10 seconds)	—	300	

Recommended Operating Conditions

The Input/Output logic timing diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The V_S offset rating is tested with all supplies biased at 15V differential.

Symbol	Parameter Definition	Value		Units
		Min.	Max.	
V _{CC}	Fixed Supply Voltage	V _S + 12	V _S + 18	V
V _S	Gate Drive Return Voltage	-5	5	
V _O	Output Voltage	V _S	V _{CC}	
V _{IN}	Logic Input Voltage	0	V _{CC}	
V _{ERR}	Error Signal Voltage	0	V _{CC}	
V _{CS}	Current Sense Signal Voltage	V _S	V _{CC}	
T _A	Ambient Temperature	-40	125	°C

Dynamic Electrical Characteristics

V_{BIAS} (V_{CC}) = 15V, C_L = 3300 pF and T_A = 25°C unless otherwise specified. The dynamic electrical characteristics are defined in Figures 2 through 5.

Symbol	Parameter Definition	Figure	Value			Units	Test Conditions
			Min.	Typ.	Max.		
t_{on}	Turn-On Propagation Delay	7	—	150	200	ns	$V_{IN} = 0 \text{ \& } 5V$
t_{off}	Turn-Off Propagation Delay	8	—	200	250		
t_{sd}	ERR Shutdown Propagation Delay	9	—	1.7	2.2	μs	
t_r	Turn-On Rise Time	10	—	43	60	ns	
t_f	Turn-Off Fall Time	11	—	26	35		
t_{cs}	CS Shutdown Propagation Delay	12	—	0.7	1.2	μs	$C_{ERR} = 270 \text{ pF}$
t_{err}	CS to ERR Pull-Up Propagation Delay	13	—	9.0	12		

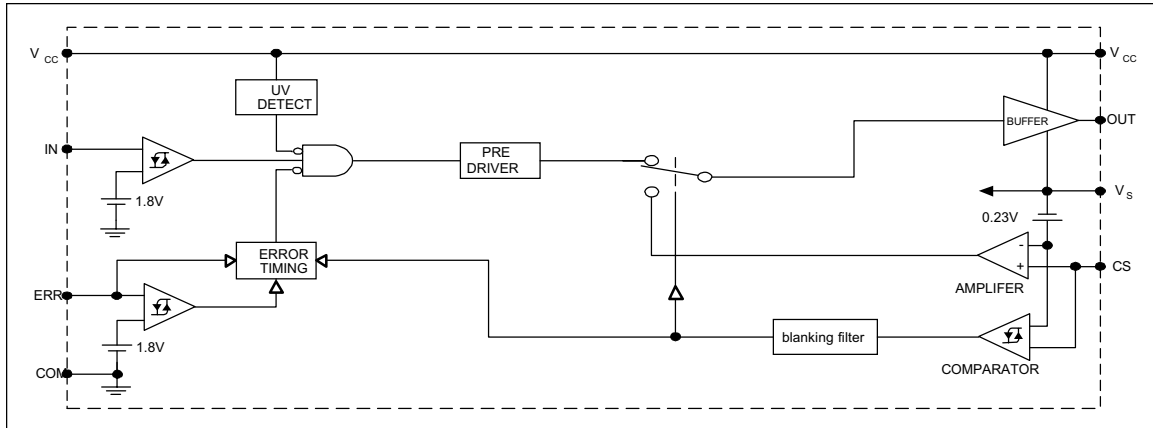
Static Electrical Characteristics

V_{BIAS} (V_{CC}) = 15V and T_A = 25°C unless otherwise specified. The V_{IN} , V_{TH} and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to V_S .

Symbol	Parameter Definition	Figure	Value			Units	Test Conditions
			Min.	Typ.	Max.		
V_{IH}	Logic "1" Input Voltage	14	2.2	—	—	V	
V_{IL}	Logic "0" Input Voltage	15	—	—	0.8		
V_{CSTH+}	CS Input Positive Going Threshold	16	150	230	320	mV	
V_{CSTH-}	CS Input Negative Going Threshold	17	130	210	300		
V_{OH}	High Level Output Voltage, $V_{BIAS} - V_O$	18	—	—	100		$I_O = 0A$
V_{OL}	Low Level Output Voltage, V_O	19	—	—	100		$I_O = 0A$
I_{QCC}	Quiescent VCC Supply Current	20	—	1.1	2.2	mA	$V_{IN} = V_{CS} = 0V$ or 5V
I_{IN+}	Logic "1" Input Bias Current	21	—	4.5	10	μA	$V_{IN} = 5V$
I_{IN-}	Logic "0" Input Bias Current	22	—	—	1.0		$V_{IN} = 0V$
I_{CS+}	"High" CS Bias Current	23	—	4.5	10		$V_{CS} = 3V$ or 5V
I_{CS-}	"Low" CS Bias Current	24	—	—	1.0		$V_{CS} = 0V$
V_{CCUV+}	V_{CC} Supply Undervoltage Positive Going Threshold	25	8.3	8.9	9.6	V	
V_{CCUV-}	V_{CC} Supply Undervoltage Negative Going Threshold	26	7.3	8.0	8.7		
I_{ERR}	ERR Timing Charge Current	27	65	100	130	μA	$V_{IN} = 5V, V_{CS} = 3V$ $ERR < V_{ERR+}$
I_{ERR+}	ERR Pull-Up Current	28	8.0	15	—	mA	$V_{IN} = 5V, V_{CS} = 3V$ $ERR > V_{ERR+}$
I_{ERR-}	ERR Pull-Down Current	29	16	30	—		$V_{IN} = 0V$
I_{O+}	Output High Short Circuit Pulsed Current	30	1.0	1.6	—	A	$V_O = 0V, V_{IN} = 5V$ $PW \leq 10 \mu s$
I_{O-}	Output Low Short Circuit Pulsed Current	31	2.0	3.3	—		$V_O = 15V, V_{IN} = 0V$ $PW \leq 10 \mu s$

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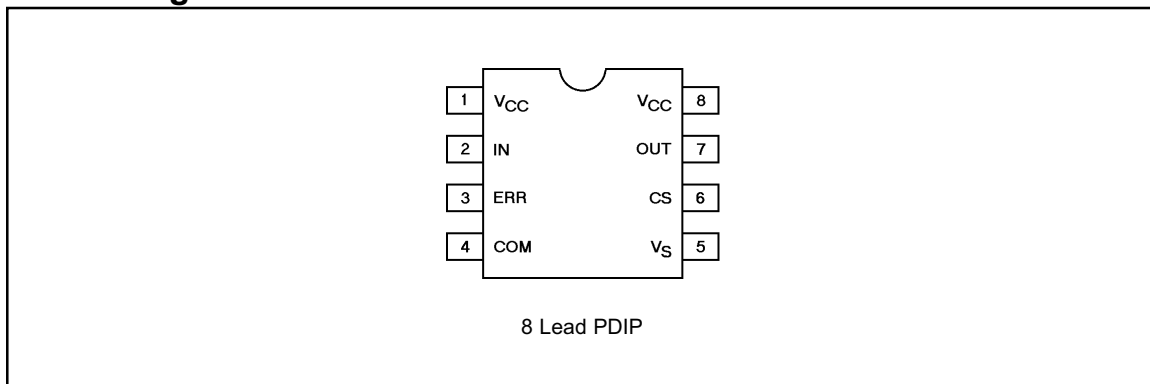
Functional Block Diagram



Lead Definitions

Lead	
Symbol	Description
V _{CC}	Logic and gate drive supply
IN	Logic input for gate driver output (OUT), in phase with OUT
ERR	Serves multiple functions; status reporting, linear mode timing and cycle by cycle logic shutdown
COM	Logic ground
OUT	Gate drive output
V _S	Gate drive supply return
CS	Current sense input to current sense comparator

Lead Assignments



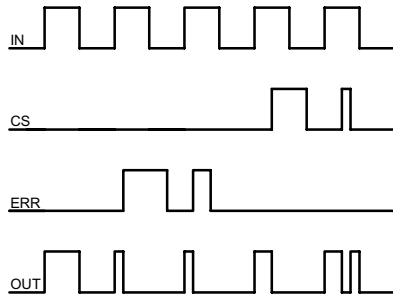


Figure 1. Input/Output Timing Diagram

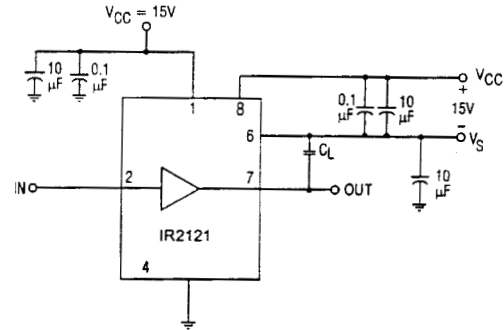


Figure 2. Switching Time Test Circuit

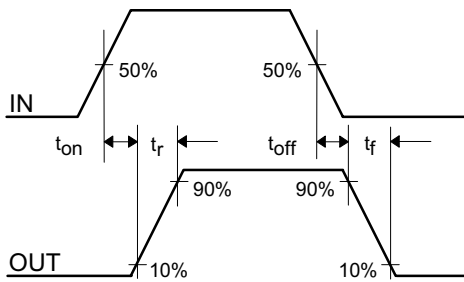


Figure 3. Switching Time Waveform Definitions

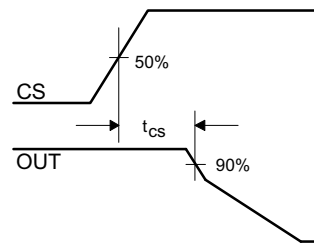


Figure 4. ERR Shutdown Waveform Definitions

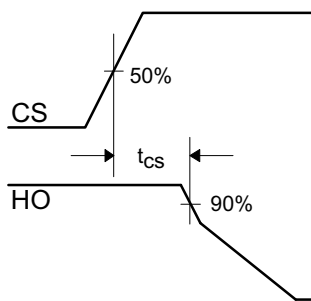
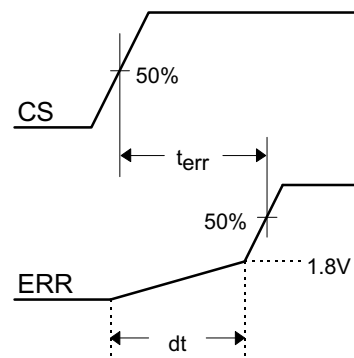


Figure 5. CS Shutdown Waveform Definitions



$$dt = C \times \frac{dV}{I_{ERR}} = C \times \frac{1.8V}{100 \mu A}$$

Figure 6. CS to ERR Waveform Definitions

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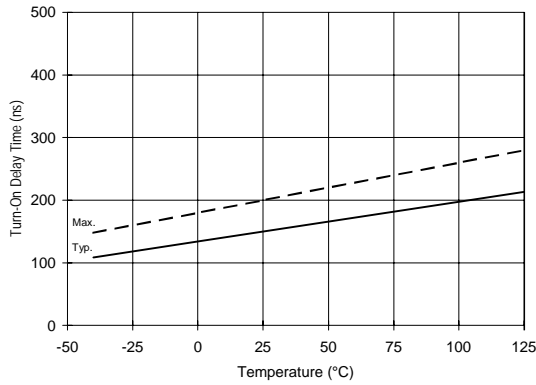


Figure 7A. Turn-On Time vs. Temperature

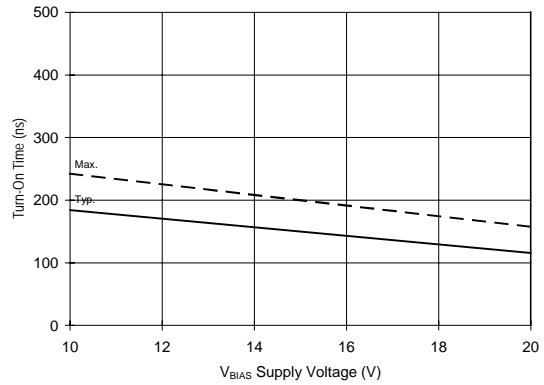


Figure 7B. Turn-On Time vs. Voltage

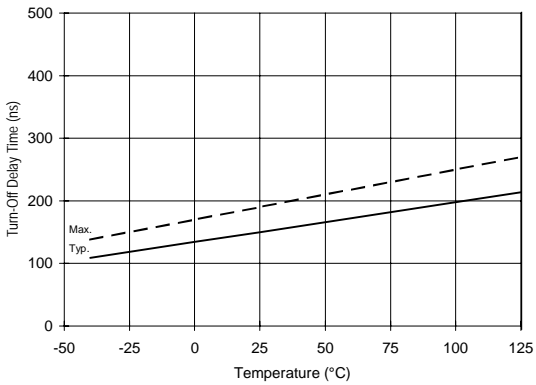


Figure 8A. Turn-Off Time vs. Temperature

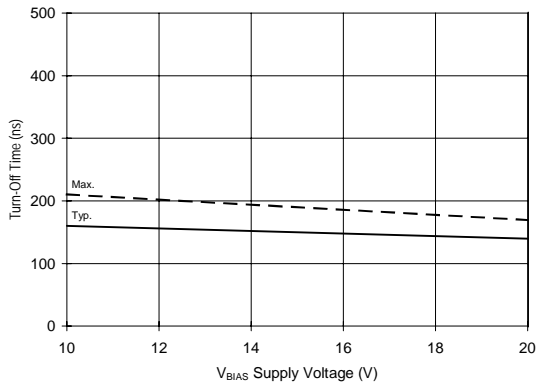


Figure 8B. Turn-Off Time vs. Voltage

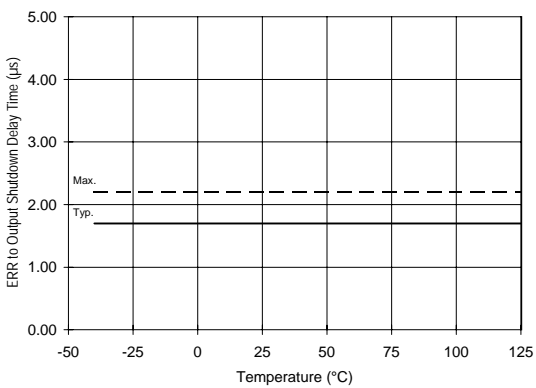


Figure 9A. ERR to Output Shutdown vs. Temperature

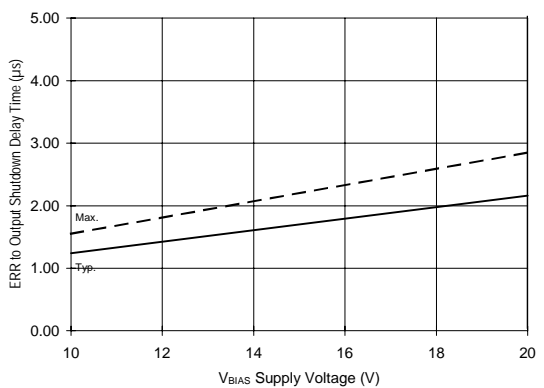


Figure 9B. ERR to Output Shutdown vs. Voltage

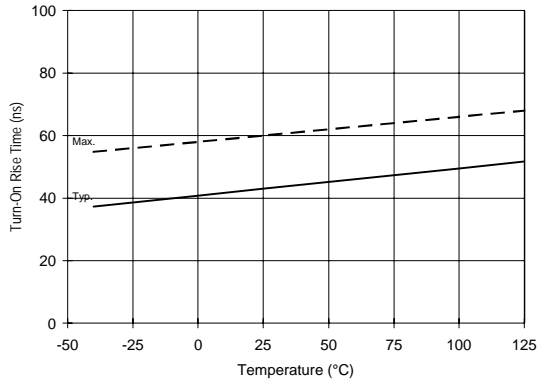


Figure 10A. Turn-On Rise Time vs. Temperature

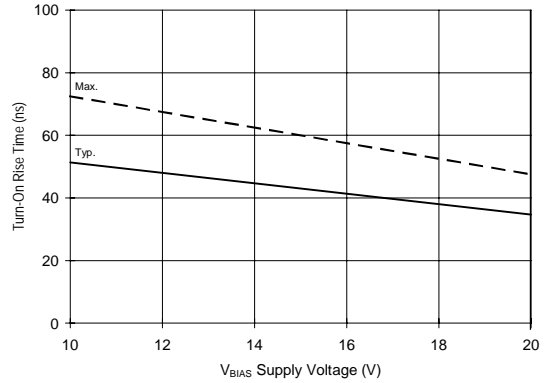


Figure 10B. Turn-On Rise Time vs. Voltage

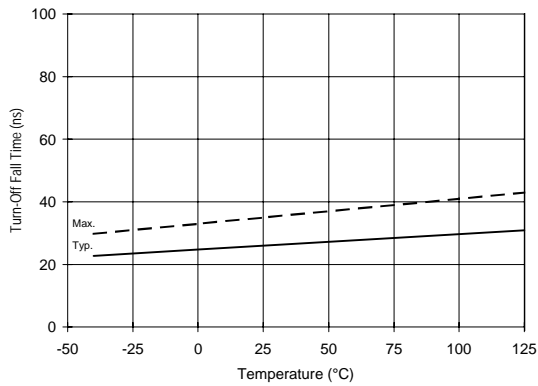


Figure 11A. Turn-Off Fall Time vs. Temperature

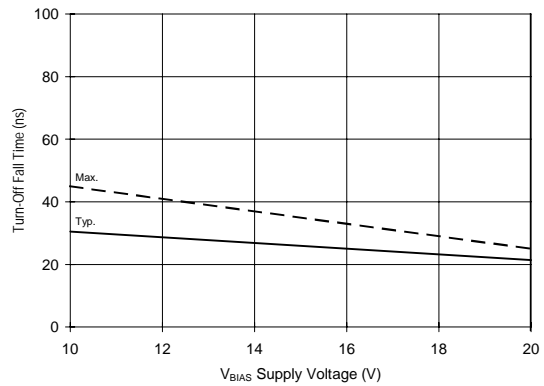


Figure 11B. Turn-Off Fall Time vs. Voltage

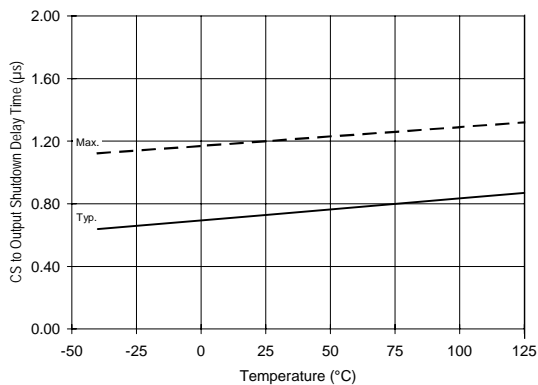


Figure 12A. CS to Output Shutdown vs. Temperature

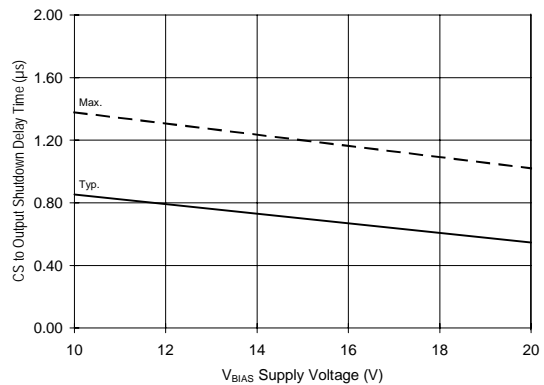


Figure 12B. CS to Output Shutdown vs. Voltage

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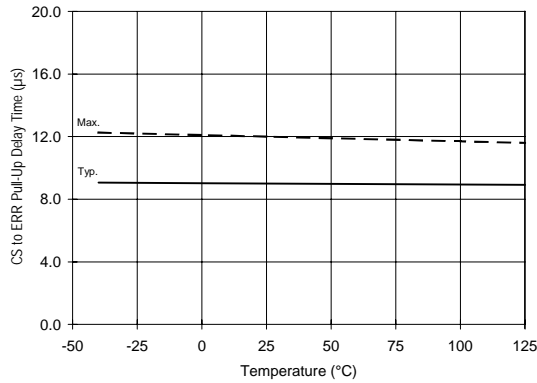


Figure 13A. CS to ERR Pull-Up vs. Temperature

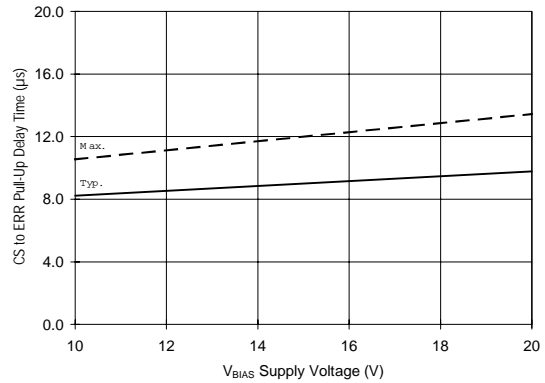


Figure 13B. CS to ERR Pull-Up vs. Voltage

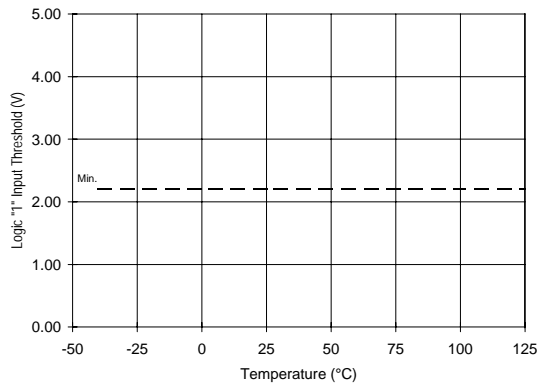


Figure 14A. Logic "1" Input Threshold vs. Temperature

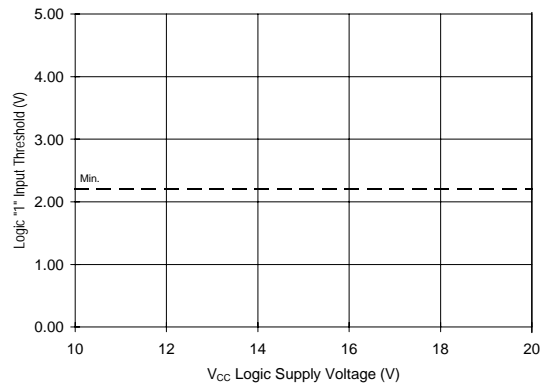


Figure 14B. Logic "1" Input Threshold vs. Voltage

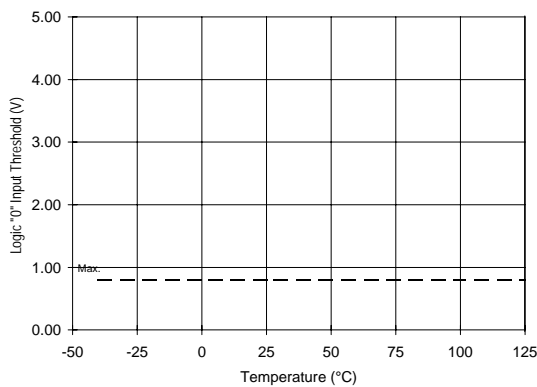


Figure 15A. Logic "0" Input Threshold vs. Temperature

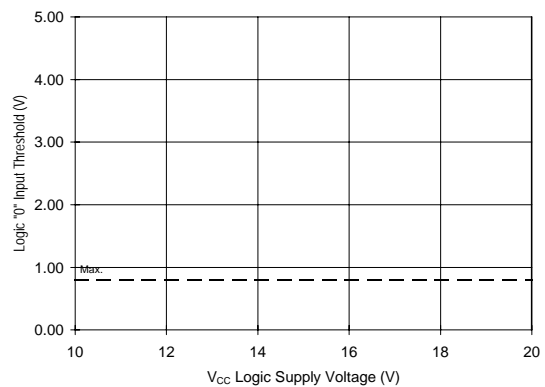


Figure 15B. Logic "0" Input Threshold vs. Voltage

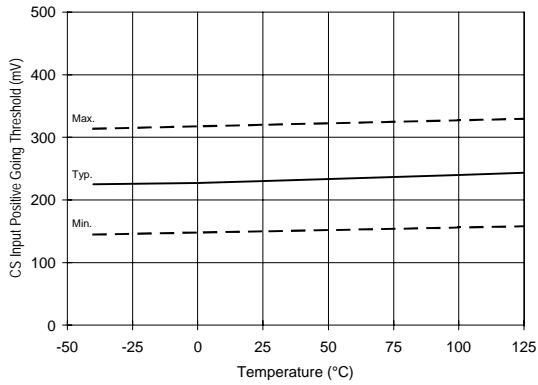


Figure 16A. CS Input Threshold (+) vs. Temperature

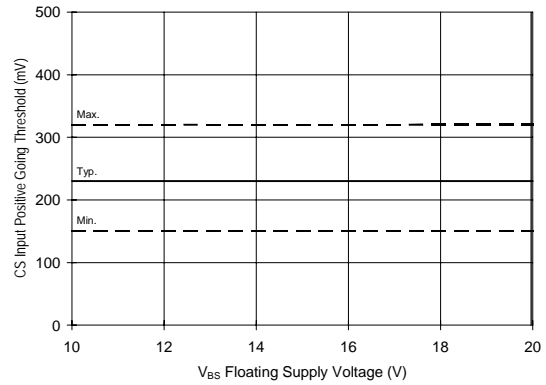


Figure 16B. CS Input Threshold (+) vs. Voltage

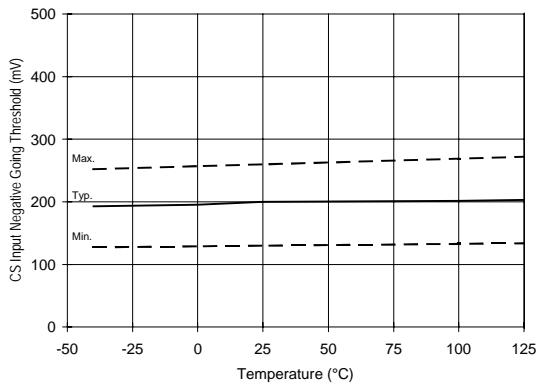


Figure 17A. CS Input Threshold (-) vs. Temperature

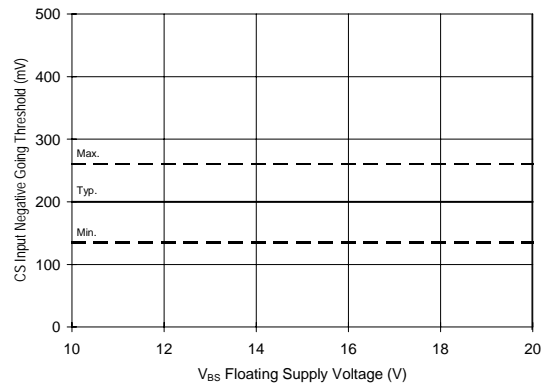


Figure 17B. CS Input Threshold (-) vs. Voltage

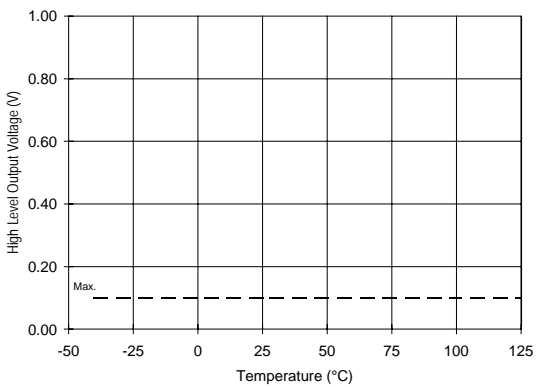


Figure 18A. High Level Output vs. Temperature

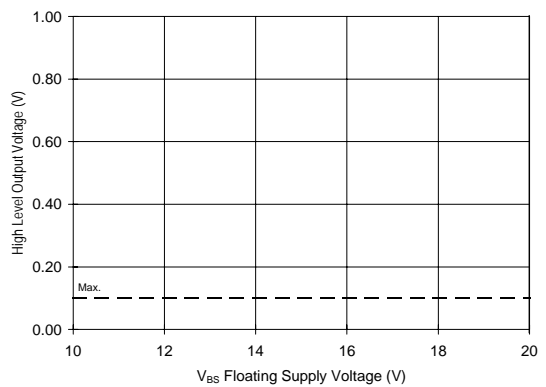


Figure 18B. High Level Output vs. Voltage

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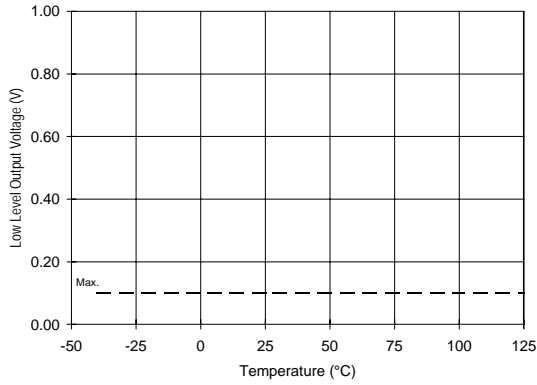


Figure 19A. Low Level Output vs. Temperature

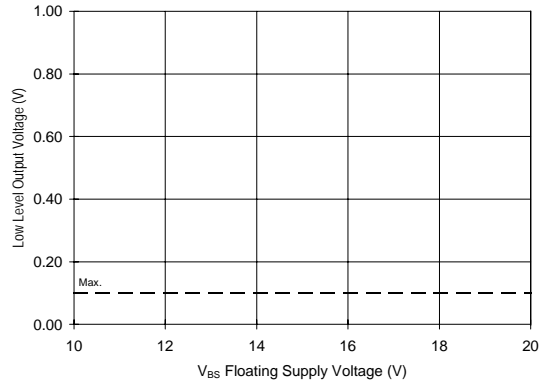


Figure 19B. Low Level Output vs. Voltage

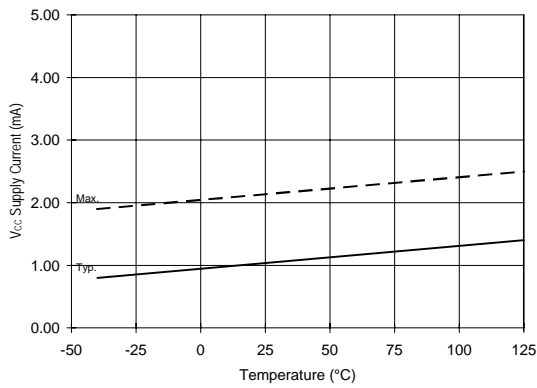


Figure 20A. V_{CC} Supply Current vs. Temperature

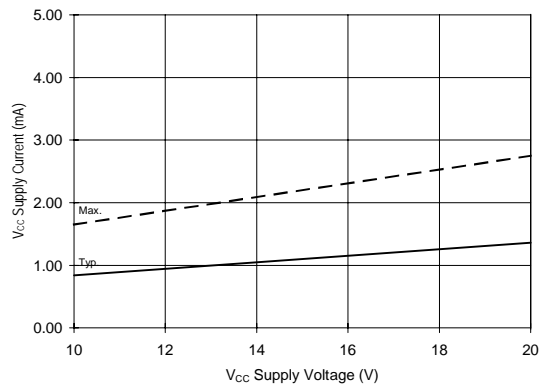


Figure 20B. V_{CC} Supply Current vs. Voltage

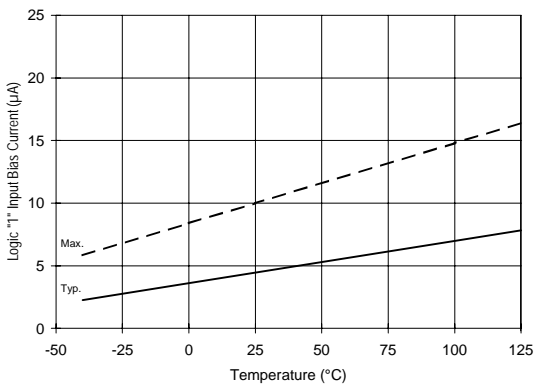


Figure 21A. Logic "1" Input Current vs. Temperature

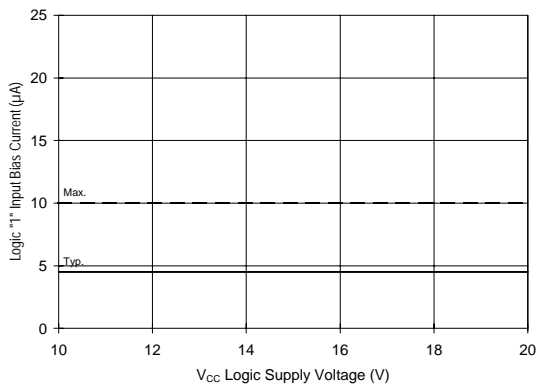


Figure 21B. Logic "1" Input Current vs. Voltage

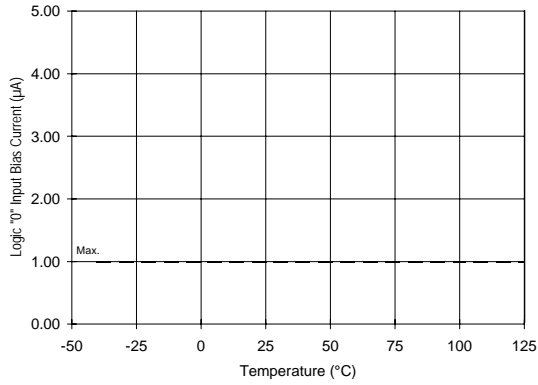


Figure 22A. Logic "0" Input Current vs. Temperature

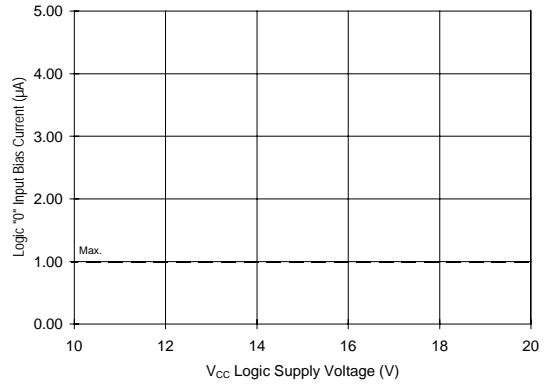


Figure 22B. Logic "0" Input Current vs. Voltage

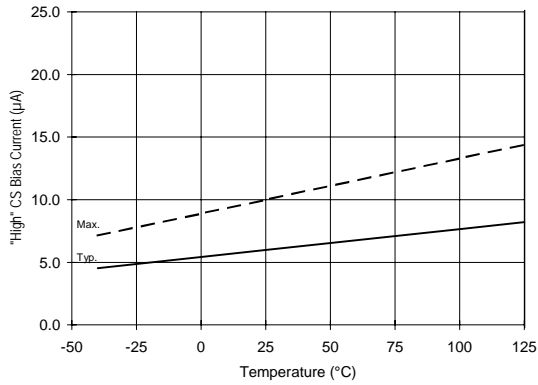


Figure 23A. "High" CS Bias Current vs. Temperature

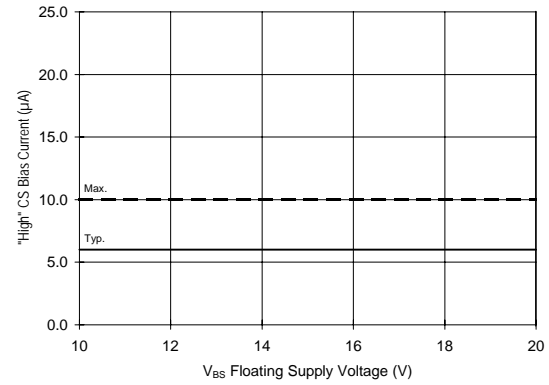


Figure 23B. "High" CS Bias Current vs. Voltage

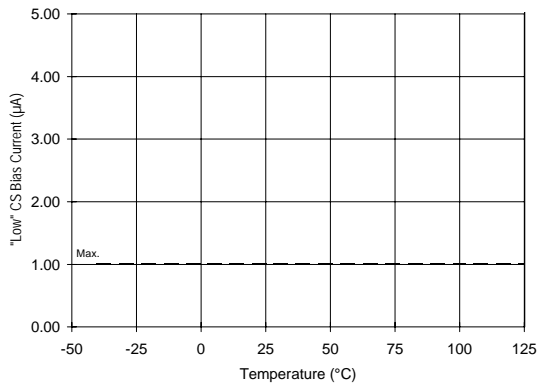


Figure 24A. "Low" CS Bias Current vs. Temperature

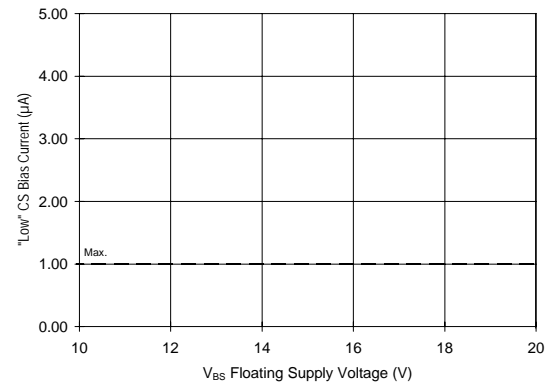


Figure 24B. "Low" CS Bias Current vs. Voltage

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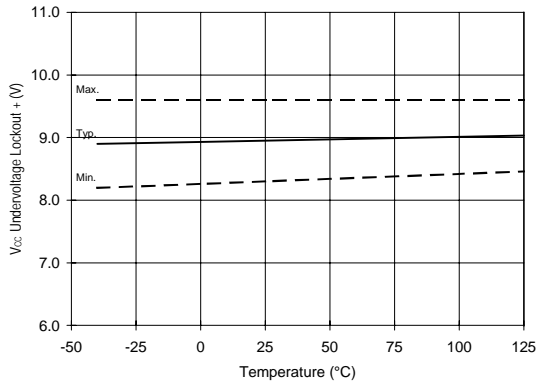


Figure 25. V_{CC} Undervoltage (+) vs. Temperature

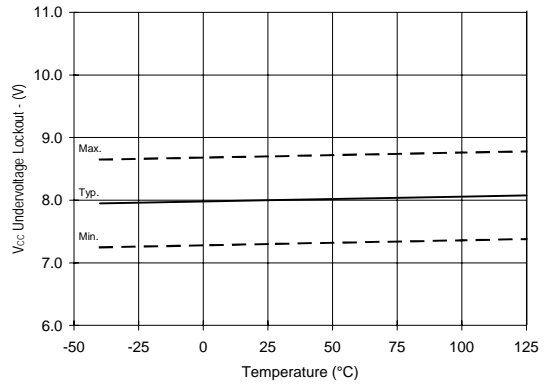


Figure 26. V_{CC} Undervoltage (-) vs. Temperature

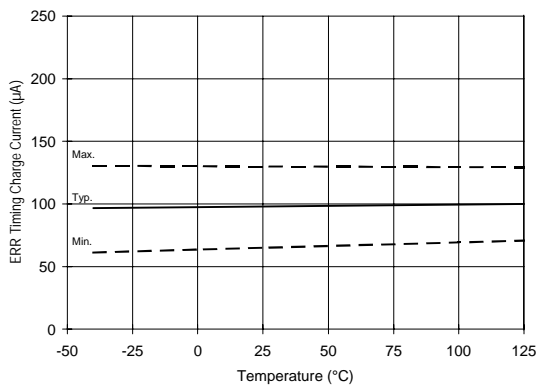


Figure 27A. ERR Timing Charge Current vs. Temperature

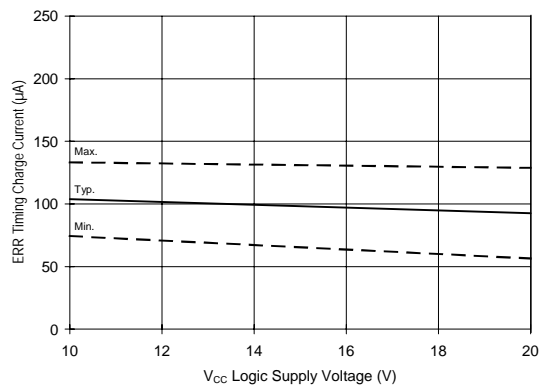


Figure 27B. ERR Timing Charge Current vs. Voltage

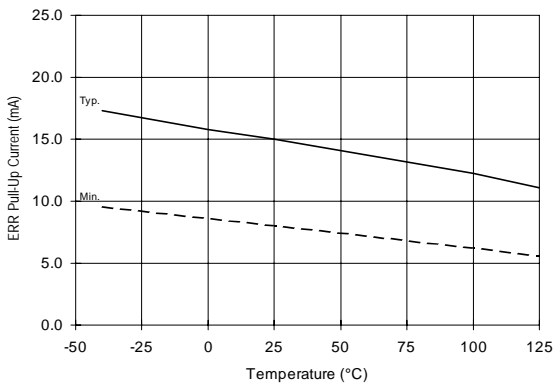


Figure 28A. ERR Pull-Up Current vs. Temperature

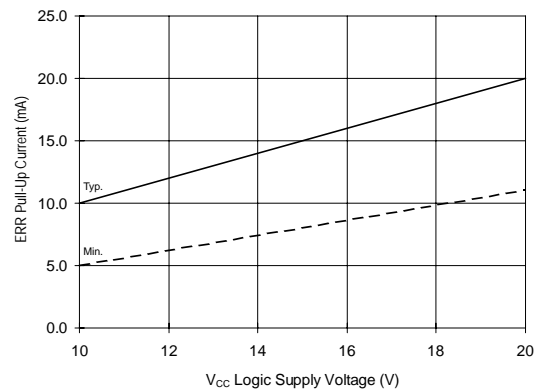


Figure 28B. ERR Pull-Up Current vs. Voltage

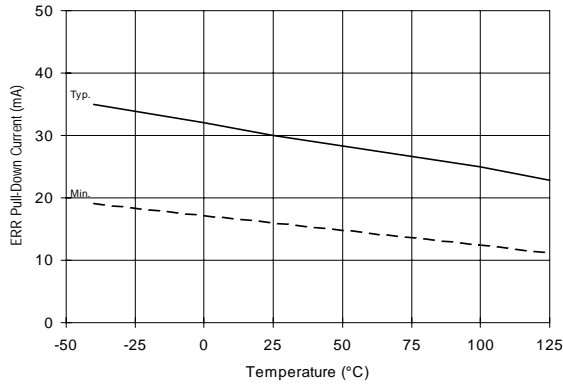


Figure 29A. ERR Pull-Down Current vs. Temperature

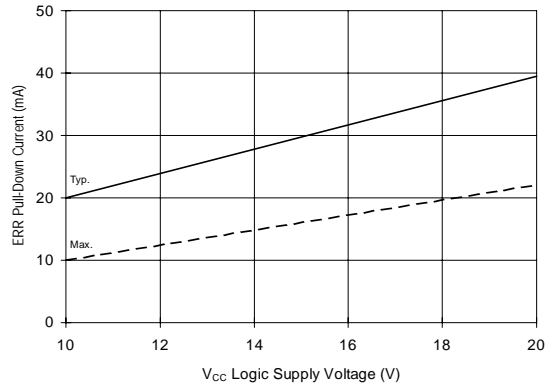


Figure 29B. ERR Pull-Down Current vs. Voltage

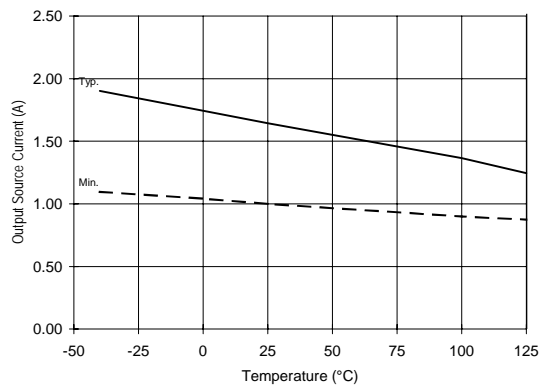


Figure 30A. Output Source Current vs. Temperature

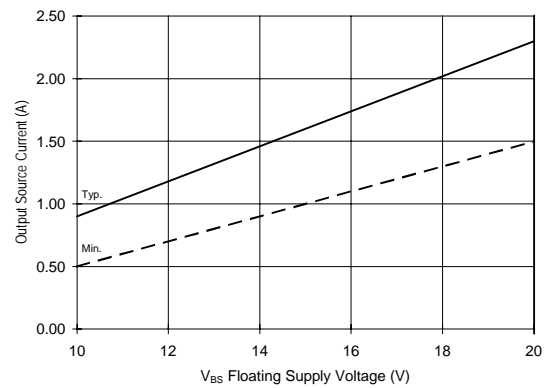


Figure 30B. Output Source Current vs. Voltage

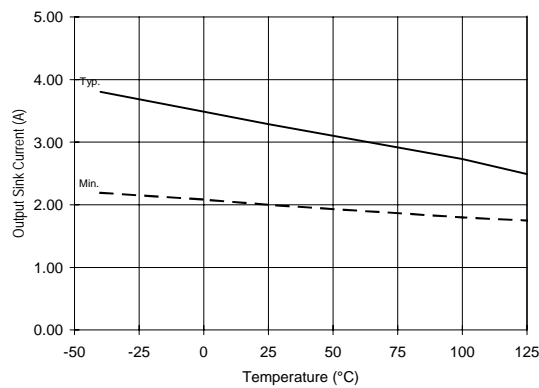


Figure 31A. Output Sink Current vs. Temperature

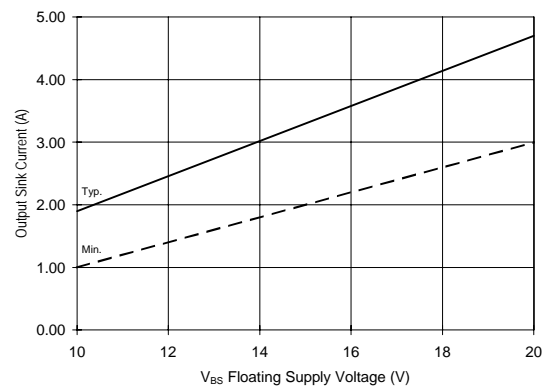


Figure 31B. Output Sink Current vs. Voltage

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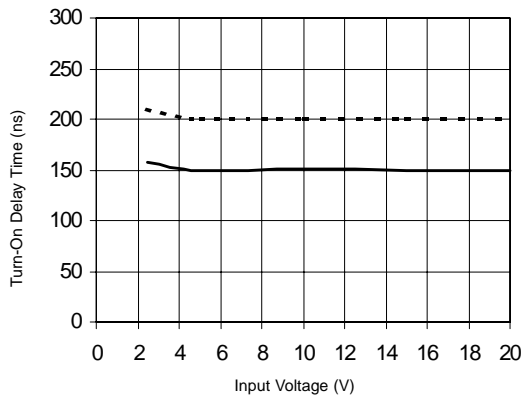


Figure 32A. Turn-On Time vs. Input Voltage

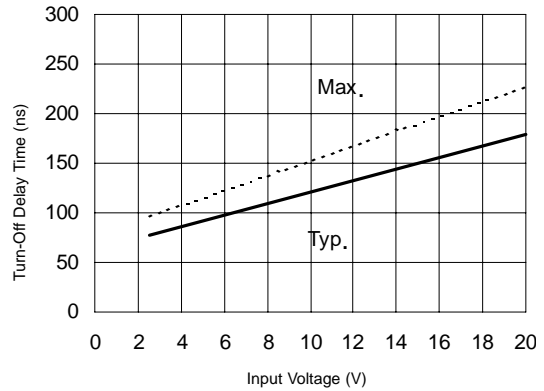


Figure 32B. Turn-Off Time vs. Input Voltage

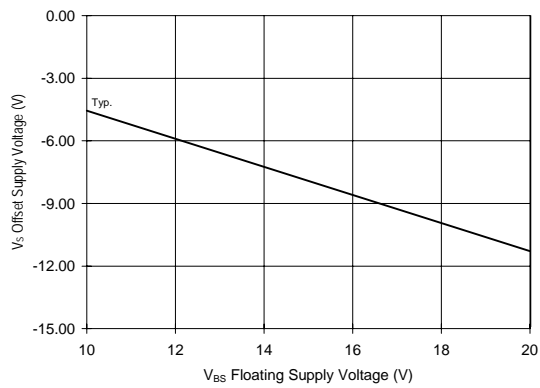
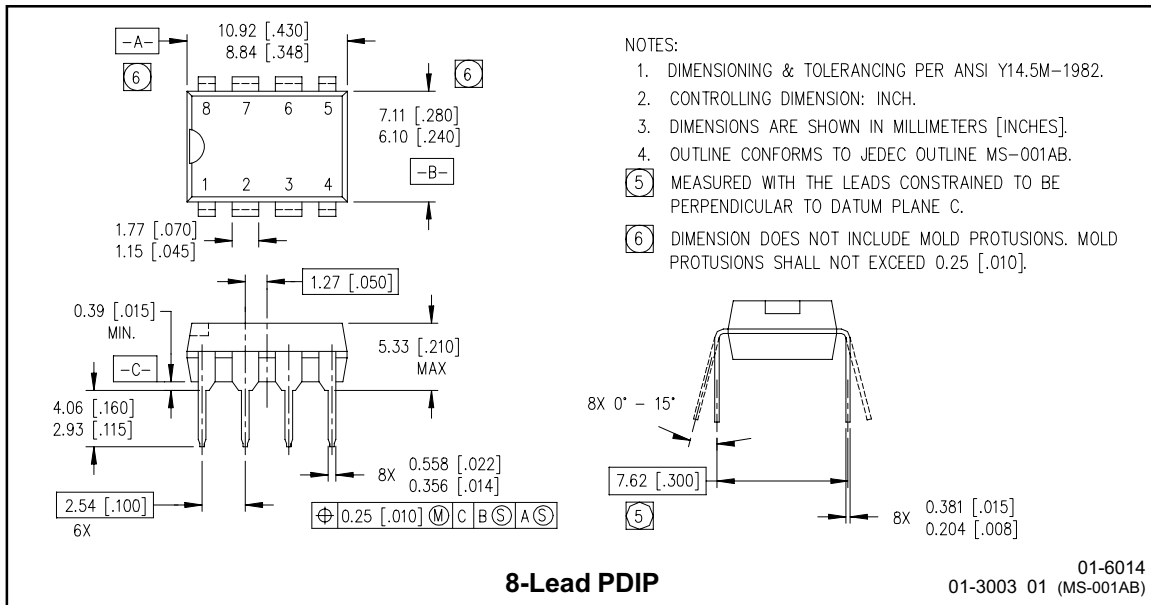


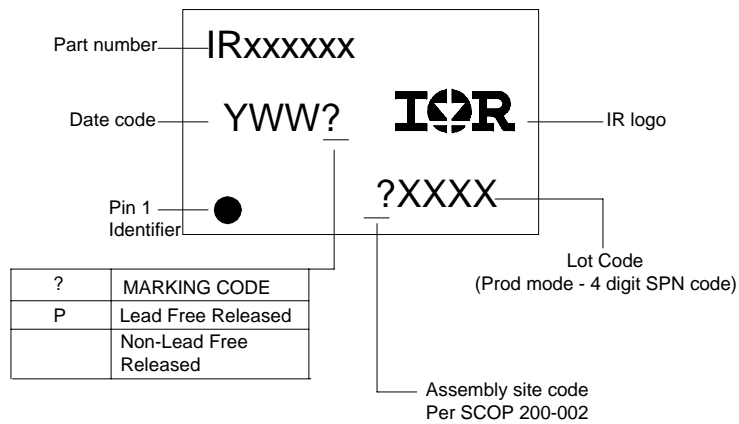
Figure 33. Maximum V_S Negative Offset vs. Supply Voltage

Case outline



IR2121 & (PbF)

LEADFREE PART MARKING INFORMATION



ORDER INFORMATION

Basic Part (Non-Lead Free)

8-Lead PDIP IR2121 order IR2121

Leadfree Part

8-Lead PDIP IR2121 order IR2121PbF

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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